NSN 5961-00-115-8561

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-00-115-8561 **Inclosure Material:** Glass **Overall Length:** 0.700 millimeters **Terminal Length:** 0.200 millimeters **Mounting Facility Quantity: Mounting Method:** Terminal **Terminal Circle Diameter:** 0.209 millimeters **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 30.0 breakdown voltage, collector to emitter, sustained and 60.0 breakdown voltage, collector-to-base, emitter open **Current Rating Per Characteristic:** 50.00 nanoamperes zero-gate-voltage source current preset **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-emitter absolute **Maximum Operating Tempurature Per Measurement Point:** -55.0 degrees celsius case and 175.0 degrees celsius case **Special Features:** High frequency low power silicon npn bjt; junction pattern arrangement: npn **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli